1-Bit Dual-Supply Inverting Level Translator

The NLSV1T240 is a 1-bit configurable dual-supply voltage level translator. The input A_n and output B_n ports are designed to track two different power supply rails, $V_{\rm CCA}$ and $V_{\rm CCB}$ respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input A_n to the output B_n port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Outputs at 3-State until Active V_{CC} is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V_{CCB} at GND
- Ultra-Small Packaging: 1.2 mm x 1.0 mm UDFN6
- This is a Pb-Free Device

Typical Applications

• Mobile Phones, PDAs, Other Portable Devices

Important Information

• ESD Protection for All Pins: Human Body Model (HBM) > 2000 V

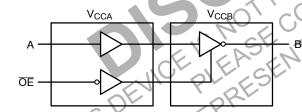
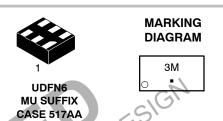


Figure 1. Logic Diagram



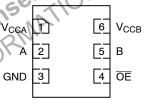
ON Semiconductor®

http://onsemi.com



- 3 = Specific Device Code
- M = Date Code
- = Pb-Free Package

PIN ASSIGNMENT



(Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
NLSV1T240MUTBG	UDFN6 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PIN ASSIGNMENT

PIN	FUNCTION
V _{CCA}	Input Port DC Power Supply
V _{CCB}	Output Port DC Power Supply
GND	Ground
Α	Input Port
В	Output Port
ŌĒ	Output Enable

TRUTH TABLE

In	Inputs				
ŌĒ	Α	В			
L	L	Н			
L	Н	L			
Н	X	3-State			

MAXIMUM RATINGS

Symbol	Rating	Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage	-0.5 to +5.5		V
VI	DC Input Voltage A	-0.5 to +5.5		V
V _C	Control Input OE	-0.5 to +5.5	CIGI.	V
Vo	DC Output Voltage (Power Down) B	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode) B	-0.5 to +5.5		V
	(Tri-State Mode) B	-0.5 to +5.5	JE"	V
I _{IK}	DC Input Diode Current	-20	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
I _O	DC Output Source/Sink Current	±50	30/1	mA
I _{CCA} , I _{CCB}	DC Supply Current Per Supply Pin	±100	Mr	mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CCA} , V _{CCB}	Positive DC Supply Voltage	0.9	4.5	٧	
VI	Bus Input Voltage	GND	4.5	٧	
V _C	Control Input	ŌĒ	GND	4.5	٧
Vio	Bus Output Voltage (Power Down Mode)	В	GND	4.5	٧
	(Active Mode)	В	GND	V _{CCB}	V
	(Tri-State Mode)	В	GND	4.5	V
T _A	Operating Temperature Range	·	-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V _I , from 30% to 70% of V _{CC} ; V _{CC} = 3.3 V \pm 0.3 V	0	10	nS	

DC ELECTRICAL CHARACTERISTICS

					-40°C t	o +85°C	
Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
V _{IH}	Input HIGH Voltage		3.6 – 4.5	0.9 – 4.5	2.2	-	V
	(A, \overline{OE})		2.7 – 3.6		2.0	_	
			2.3 – 2.7		1.6	_	
			1.4 – 2.3		0.65 * V _{CCA}	_	
			0.9 – 1.4		0.9 * V _{CCA}	_	
V _{IL}	Input LOW Voltage		3.6 – 4.5	0.9 – 4.5	-	0.8	٧
	(A, \overline{OE})		2.7 – 3.6	1	-	0.8	1
			2.3 – 2.7	1	-	0.7	1
			1.4 – 2.3	1	-	0.35 * V _{CCA}	1
			0.9 – 1.4	1	-	0.1 * V _{CCA}	1
V _{OH}	Output HIGH Voltage	$I_{OH} = -100 \mu A; V_I = V_{IL}$	0.9 – 4.5	0.9 – 4.5	V _{CCB} - 0.2	No	V
		$I_{OH} = -0.5 \text{ mA}; V_I = V_{IL}$	0.9	0.9	0.75 * V _{CCB}	SIE	1
		$I_{OH} = -2 \text{ mA}; V_I = V_{IL}$	1.4	1.4	1.05	-	
		$I_{OH} = -6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	1,25	-	
			2.3	2.3	2.0	_	
		$I_{OH} = -12 \text{ mA}; V_I = V_{IL}$	2.3	2.3	1.8	-	1
			2.7	2.7	2.2	-	
		$I_{OH} = -18 \text{ mA}; V_I = V_{IL}$	2.3	2,3	1.7	_	
			3.0	3.0	2.4	_	
		$I_{OH} = -24 \text{ mA}; V_l = V_{IL}$	3.0	3.0	2.2	-	
V _{OL}	Output LOW Voltage	$I_{OL} = 100 \mu\text{A}; V_{I} = V_{IH}$	0.9 – 4.5	0.9 – 4.5	-	0.2	V
		$I_{OL} = 0.5 \text{ mA}; V_I = V_{IH}$	1.0	1.1	-	0.3	
		$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	-	0.35	
	15	$I_{OL} = 6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	-	0.3	
	No Mi	I_{OL} = 12 mA; V_I = V_{IH}	2.3	2.3	_	0.4	
	Input Leakage Current	SYNTH	2.7	2.7	-	0.4	
	"ICE OF E	I _{OL} = 18 mA; V _I = V _{IH}	2.3	2.3	_	0.6	
	EN Prop		3.0	3.0	-	0.4	
	COV CPT	I_{OL} = 24 mA; V_I = V_{IH}	3.0	3.0	-	0.55	
lı ,	Input Leakage Current		0.9 - 4.5	0.9 – 4.5	-1.0	1.0	μΑ
l _{OFF}	Power-Off Leakage Current	<u>OE</u> = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μΑ
I _{CCA}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΑ
I _{CCB}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΑ
CCA + ICCB	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	2.0	μΑ
ΔI _{CCA}	Increase in I _{CC} per Input Voltage, Other Inputs at V _{CCA} or GND	$V_I = V_{CCA} - 0.6 V;$ $V_I = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μΑ
ΔI_{CCB}	Increase in I_{CC} per Input Voltage, Other Inputs at V_{CCA} or GND	$V_I = V_{CCA} - 0.6 \text{ V};$ $V_I = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μΑ
I _{OZ}	I/O Tri-State Output Leakage Current	$T_A = 25^{\circ}C, \overline{OE} = 0 \text{ V}$	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μΑ

TOTAL STATIC POWER CONSUMPTION (I_{CCA} + I_{CCB})

	-40°C to +85°C										
					V _{CCI}	₃ (V)					
	4.	.5	3	.3	2.	.8	1.	.8	0.9		
V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μΑ
3.3		2		2		2		2		< 1.5	μΑ
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μΑ
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μΑ
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μΑ

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB}. This device is designed with the feature that the power–up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

							-40°C to	+85°C				~	
							V _{CCI}	₃ (V)	4			101	
			4.	.5	3.	3	2.	.8	1.	.8	1	2	
Symbol	Parameter	V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation	4.5		1.6		1.8		2.0	1	2.1		2.3	nS
t _{PHL} (Note 1)	Delay,	3.3		1.7		1.9		2.1	R	2.3		2.6	
(Note 1)	A to B	2.8		1.9		2.1		2.3),	2.5	17	2.8	
		1.8		2.1		2.4		2.5	250	2.7)	3.0	
		1.2		2.4		2.7	ZD,	2.8	No	3.0		3.3	
t _{PZH} ,	Output	4.5		2.6		3.8		4.0	2/4	4.1		4.3	nS
t _{PZL} (Note 1)	Enable,	3.3		3.7	ON	3.9	40,	4.1		4.3		4.6	
(Note 1)	OE to B	2.5		3.9	7	4.1	R	4.3		4.5		4.8	
		1.8		4.1	1/1	4.4	Ο,	4.5		4.7		5.0	
		1.2	(O)	4.4), '(4.7		4.8		5.0		5.3	
t _{PHZ} ,	Output	4.5	76	2.6	1/2	3.8		4.0		4.1		4.3	nS
t _{PLZ} (Note 1)	Disable,	3.3	· Do	3.7	/,	3.9		4.1		4.3		4.6	
(Note 1)	OE to B	2.5		3.9		4.1		4.3		4.5		4.8	
	OF	1.8	27	4.1		4.4		4.5		4.7		5.0	
	115	1.2		4.4		4.7		4.8		5.0		5.3	
t _{OSHL} ,	Output to	4.5		0.15		0.15		0.15		0.15		0.15	nS
t _{OSLH}	Output Skew,	3.3		0.15		0.15		0.15		0.15		0.15	
(Note 1)	Time	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

^{1.} Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C _{IN}	Control Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	3.5	pF
C _{I/O}	I/O Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CCA}, f = 10 \text{ MHz}$	5.0	pF

Typical values are at T_A = +25°C.
 C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I_{CC(operating)} ≅ C_{PD} x V_{CC} x f_{IN} where I_{CC} = I_{CCA} + I_{CCB}.

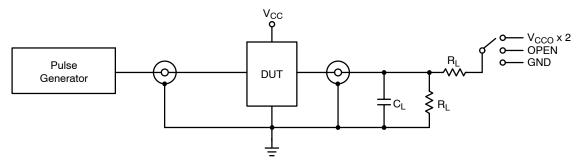


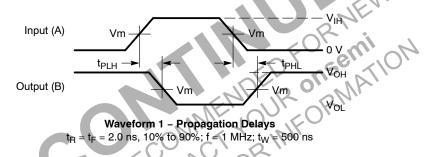
Figure 2. AC (Propagation Delay) Test Circuit

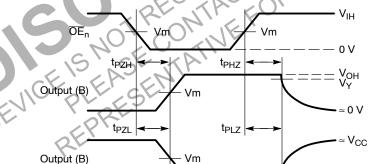
Test	Switch
t _{PLH} , t _{PHL}	OPEN
t_{PLZ} , t_{PZL}	V _{CCO} x 2
t _{PHZ} , t _{PZH}	GND

C_L = 15 pF or equivalent (includes probe and jig capacitance)

 R_L = 2 $k\Omega$ or equivalent

 Z_{OUT} of pulse generator = 50 Ω





Waveform 2 – Output Enable and Disable Times $t_R = t_F = 2.0 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

Figure 3. AC (Propagation Delay) Test Circuit Waveforms

	V _{CC}					
Symbol	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V	
V _{mA}	V _{CCA} /2					
V _{mB}	V _{CCB} /2					
V _X	V _{OL} x 0.1					
V _Y	V _{OH} x 0.9					

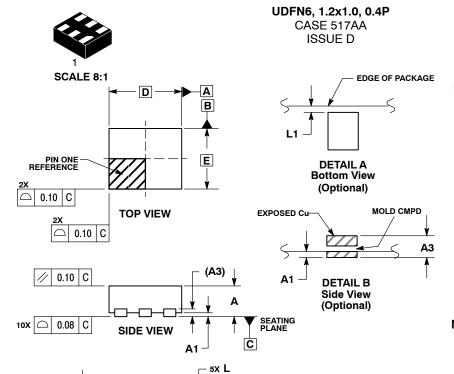


6X **b**

0.10 | C | A | B

0.05 C

NOTE 3



е

BOTTOM VIEW

DATE 03 SEP 2010

NOTES:

- DIMENSIONING AND TOLERANCING PER
 ASME Y14 5M 1994
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND
 TO THE PROPERTY OF THE PROPER
- 0.30 mm FROM TERMINAL.
 COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIM	ETERS		
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
A3	0.127	REF		
b	0.15	0.25		
D	1.20	BSC		
E	1.00	BSC		
е	0.40	BSC		
L	0.30	0.40		
L1	0.00	0.15		
L2	0.40	0.50		

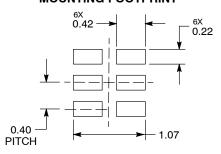
GENERIC MARKING DIAGRAM*



X = Specific Device CodeM = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present.

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	6 PIN UDFN, 1.2X1.0, 0.4P		PAGE 1 OF 1

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